



Docket No.: 21737-00013-US
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Katsuki Hazama

Application No.: 09/438,295

Confirmation No.: 9121

Filed: November 12, 1999

Art Unit: 2135

For: MULTILEVEL SEMICONDUCTOR MEMORY WRITE/
READ METHOD THERETO/THEREFROM AND
STORAGE MEDIUM STORING WRITE/READ PRO-
GRAM

Examiner: L. Hua

CHANGE OF CORRESPONDENCE ADDRESS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In accordance with the Manual of Patent Examining Procedures, Section 601.03, please change the mailing address for all correspondence in the above-identified patent application to:

George R. Pettit
CONNOLLY BOVE LODGE & HUTZ LLP
1990 M Street, N.W., Suite 800
Washington, DC 20036-3425
(202) 331-7111

Please direct all further communications to the above-identified firm.


Application No.: 09/438,295

Docket No.: 21737-00013-US

Applicant believes no fee is due with this response. However, if a fee is due, please charge our Deposit Account No. 22-0185, under Order No. 21737-00013-US from which the undersigned is authorized to draw.

Dated: 12/01/04

Respectfully submitted,

By 
George R. Pettit, Reg. No. 27,369
CONNOLLY BOVE LODGE & HUTZ LLP
1990 M Street, N.W., Suite 800
Washington, DC 20036-3425
(202) 331-7111
(202) 293-6229 (Fax)
Attorney for Applicant